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Product Quality Quick Reference Information

Quality information for product types

Quality and reliability data provided by Nexperia is intended to be a non-binding estimate of product performance only. It does not imply that any performance levels reflected in such data can be met if the product is operated outside the conditions expressly stated in the latest published datasheet for a device or in your application.

Quick reference

Information	Content
Device type	PXN2R9-100RS
Orderable part number (12NC)	934666162118
Package	SOT8038-1
Waferfab sites	UNT, China
Assembly sites	ATX, China
ESD HBM	4000V - 8000V (3A)
ESD CDM	NA

The ESD values shown are typical representative numbers from a sample of devices tested during qualification and not guaranteed. Measurements have been conducted in accordance with JS-001-2017.

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Reliability qualification information

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Stress	Conditions	Duration	Quantity	Rejects
Stress Pre and Post stress electrical test	T_{amb} = 25°C	N/A	All parts	See below
PC Preconditioning	JESD22-A113 Bake T_{amb} = 125°C Soak T_{amb} = 85°C, RH = 85% reflow	24 hours 168 hours 3 cycles	270	0
HTRB High temperature reverse bias	MIL-STD-750-1 T_j = T_j max, V_{DS} = 80% of rated Voltage M1039 Method A	1000 hours	90	0
HTGB High temperature gate bias	JESD22-A108 T_j = T_j max, V_{GS} = 16V	1000 hours	90	0
TC Temperature Cycling	JESD22-A104 -40°C to 125°C	850 cycles	90	0
H3TRB Temperature Humidity bias	JESD22-A101 T_{amb} = 85°C, RH = 85% V_{DS} = 80% of rated voltage	1000 hours	90	0
IOL Intermittent operating life	MIL-STD-750 method 1037 ΔTj = 80°C	5000 cycles	90	0
RSH Resistance to solder heat	JESD22-A111 (SMD) 260°C ± 5°C	10s	30	0
SD Solderability	IPC/ECA J-STD-002 Method A dip and look No aging, solder Ta = 245°C	3 sec dip	30	0
	IPC/ECA J-STD-002 Method B dip and look No aging, Solder Ta = 245°C >95% lead coverage required Steam Aging: condition C Steam Ta = 93°C, 8 hours Solder Ta = 245°C, 3 sec dip	8 hours 3 sec dip	30	0
	Dry Bake: Ta = 150°C Solder Ta = 245°C >95% lead coverage required	16 hours 3 sec dip	30	0

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Calculation of FIT and MTBF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB) and High temperature Gate Bias (HTGB). Confidence level 60%, derated to 55°C, activation energy 0.7eV test time 168 to 1000 hours.

Technology	Quantity	Failure rate	MTBF
UNT_SGT_G1	180	39.1	2.56E+07

Structural Similarity Grouping

For qualification testing Nexperia uses the Qualification Family approach, also referred to as 'Structural Similarity Grouping' (SSG), meaning the products in the family share the same major process and material elements.

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